COMPLIANT

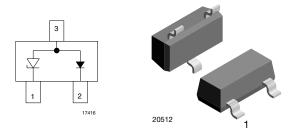
HALOGEN FREE

**GREEN** 



Vishay Semiconductors

# Low Capacitance ESD Protection Diodes for High-Speed Data Interfaces



## **MARKING** (example only)



Bar = cathode marking YYY = type code (see table below) XX = date code

#### **FEATURES**

- IEC 61000-4-5 (lightning) see I<sub>PPM</sub> below
- ESD-protection acc. IEC 61000-4-2
   ± 8 kV contact discharge
  - ± 15 kV air discharge
- ESD capability according to AEC-Q101: human body model: class H3B: > 8 kV
- SOT-23 package
- High temperature soldering guaranteed: 260 °C/10 s at terminals
- Low capacitance for high speed data lines, cellular handsets, USB port protection, LAN equipment, peripherals
- e3 Sn
- AEC-Q101 qualified available
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

ORDERIN	ORDERING INFORMATION								
	ENVIR	ONMENTAL AN	ID QUALITY C	ODE	PACKAG	ING CODE			
PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	RoHS-COMPLIANT + LEAD (Pb)-FREE		TIN	3K PER 7" REEL (8 mm TAPE),	10K PER 13" REEL (8 mm TAPE),	ORDERING CODE (EXAMPLE)		
(=/0 ==/	QUALIFIED	STANDARD	GREEN	PLATED		10K/BOX = MOQ			
GL05T-		E		3	-08		GL05T-E3-08		
GL05T-			G	3	-08		GL05T-G3-08		
GL05T-	Н	E		3	-08		GL05T-HE3-08		
GL05T-	Н		G	3	-08		GL05T-HG3-08		
GL05T-		E		3		-18	GL05T-E3-18		
GL05T-			G	3		-18	GL05T-G3-18		
GL05T-	Н	E		3		-18	GL05T-HE3-18		
GL05T-	Н		G	3		-18	GL05T-HG3-18		

PACK	PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS	
GL05T	SOT-23	L05	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GLOST	301-23	L06	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GL12T	SOT-23	L12	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GLIZI	L121 SO1-23		Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GL15T	SOT-23	L15	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GLIST	301-23	L16	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GL24T	SOT-23	L24	Standard	8.8 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	
GLZ41	001-20	L25	Green	8.1 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals	

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ABSOLUTE MAXIMUM RATINGS GL05T							
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT		
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	25	Α		
Peak pulse power	8/20 µs waveform	Ρπ 1-2 (μπ 3 π.υ.)	P <sub>PP</sub>	300	W		
ESD immunity	Contact discharge	acc. IEC 61000-4-2; 10 pulses	V	± 8	kV		
ESD Illillidility	Air discharge acc.	IEC 61000-4-2; 10 pulses	$V_{ESD}$	± 8 ± 15	kV		
Blocking voltage	I <sub>B</sub> = 1 μA	Pin 2-1 or pin 2-3	V <sub>B</sub>	70	V		
Operating temperature	Junction temperatu	Junction temperature		-55 to +150	°C		
Storage temperature				-55 to +150	°C		

ABSOLUTE MAXIMUM RATINGS GL12T						
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT	
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	12	Α	
Peak pulse power	8/20 µs waveform	Pin 1-2 (pin 3 n.c.)	P <sub>PP</sub>	300	W	
ESD immunity	Contact discharge	Contact discharge acc. IEC 61000-4-2; 10 pulses		± 8	kV	
ESD Illillidility	Air discharge acc. I	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV	
Blocking voltage	I <sub>B</sub> = 1 μA	Pin 2-1 or pin 2-3	V <sub>B</sub>	70	V	
Operating temperature	Junction temperatu	Junction temperature		-55 to +150	°C	
Storage temperature			T <sub>STG</sub>	-55 to +150	°C	

ABSOLUTE MAXIMUM RATINGS GL15T							
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT		
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	10	Α		
Peak pulse power	8/20 µs waveform	Pin 1-2 (pin 3 n.c.)	P <sub>PP</sub>	300	W		
FOD :	Contact discharge	acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	± 8	kV		
ESD immunity	Air discharge acc. I	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV		
Blocking voltage	$I_B = 1 \mu A$	Pin 2-1 or pin 2-3	V <sub>B</sub>	70	V		
Operating temperature	Junction temperatu	Junction temperature		-55 to +150	°C		
Storage temperature			T <sub>STG</sub>	-55 to +150	°C		

ABSOLUTE MAXIMUI	M RATINGS GL24	т			
PARAMETER	TEST	TEST CONDITIONS		VALUE	UNIT
Peak pulse current	8/20 µs	Pin 1-2 (pin 3 n.c.)	I <sub>PPM</sub>	5	Α
Peak pulse power	8/20 µs waveform	ΕΠ 1-2 (βΠ 3 Π.Ε.)	P <sub>PP</sub>	300	W
ESD immunity	Contact discharge	Contact discharge acc. IEC 61000-4-2; 10 pulses		± 8	kV
LSD initiality	Air discharge acc. I	EC 61000-4-2; 10 pulses	$V_{ESD}$	± 15	kV
Blocking voltage	I <sub>B</sub> = 1 μA	Pin 2-1 or pin 2-3	V <sub>B</sub>	70	V
Operating temperature	Junction temperatu	re	TJ	-55 to +150	°C
Storage temperature			T <sub>STG</sub>	-55 to +150	°C

The GLxxT contains an avalanche diode (pin 3-1) and a switching diode (pin 3-2). With pin 1 connected to the signal or data line and pin 2 connected to ground both diodes are in series (pin 3 remains unconnected). The big and robust avalanche diode, driven in reverse direction, provides the working range V<sub>RWM</sub> of 5 V, 12 V, 15 V or 24 V. Due to its size the capacitance of the avalanche diode is in the range of typ. 260 pF (GL05T) and 65 pF (GL24T). The small switching diode in series has a low capacitance of just 2.5 pF (typ.). As both diodes are in series (with pin 3 not connected) the total capacitance of both diodes measured between pin 1 and 2 is as low as the capacitance of the switching diode.

Before the GLxxT can provide this low capacitance the big capacitance of the avalanche diode has to be charged up with the first signal or data pulses. This is usually no problem for digital signals like USB or other data ports.

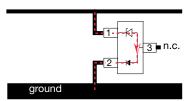
With the GLxxT a signal or data line can be protected against positive transients only. For negative transients another GLxxT can be used to provide a back path for the negative transients as well.



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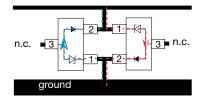
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#### Data line



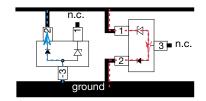
# Uni Unidirectional clamping performance for positive transients only.

#### Data line



BiSy
Bidirectional and Symmetrical
clamping performance for positive
and negative transients.

#### Data line



BiAs

**Bi**directional and **As**ymmetrical clamping performance for positive and negative transients.

<b>ELECTRICAL CHARACTERISTICS GL05T</b> (T <sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	5	V		
Reverse voltage	at I <sub>R</sub> = 20 μA	V <sub>R</sub>	5	-	-	V		
Reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	-	20	μΑ		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6.9	7.5	8.0	V		
Deverse elemning valtage	at I <sub>PP</sub> = 1 A	V	-	-	9.8	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	11	V		
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	-	2.5	5	pF		

<b>ELECTRICAL CHARACTERISTICS GL12T</b> (T <sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	12	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	$V_{R}$	12	-	-	V		
Reverse current	at V <sub>R</sub> = 12 V	I <sub>R</sub>	-	-	1	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	13.3	14.3	17.2	V		
Poverse clamping voltage	at I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	-	19	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	VC	-	-	24	V		
Capacitance	at V <sub>R</sub> = 0 V; f = 1 MHz	C <sub>D</sub>	-	2.5	5	pF		

<b>ELECTRICAL CHARACTERISTICS GL15T</b> (T <sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	15	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	$V_{R}$	15	-	-	V		
Reverse current	at V <sub>R</sub> = 15 V	I <sub>R</sub>	-	-	1	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	16.7	17.7	22	V		
Payaraa alamping valtaga	at I <sub>PP</sub> = 1 A	V	-	-	24	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	33	V		
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	-	2.5	5	pF		



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<b>ELECTRICAL CHARACTERISTICS GL24T</b> (T <sub>amb</sub> = 25 °C unless otherwise specified) pin 1 to pin 2; pin 3 not connected								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand-off voltage	Max. reverse working voltage	V <sub>RWM</sub>	=	-	24	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	V <sub>R</sub>	24	-	-	V		
Reverse current	at V <sub>R</sub> = 24 V	I <sub>R</sub>	=	-	1	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	26.7	28.2	33	V		
Payaras alamping valtage	at I <sub>PP</sub> = 1 A	V	=	-	43	V		
Reverse clamping voltage	at I <sub>PP</sub> = 5 A	V <sub>C</sub>	-	-	55	V		
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	-	2.5	5	pF		

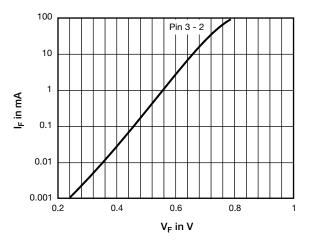


Fig. 1 - Typical Forward Current  $I_F$  vs. Forward Voltage  $V_F$ 

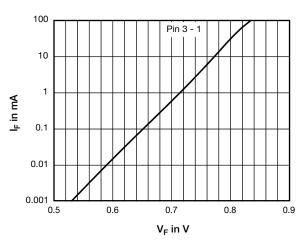


Fig. 2 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

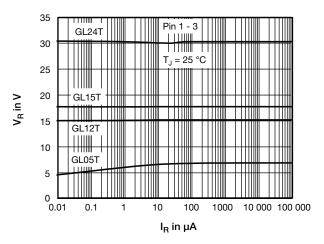


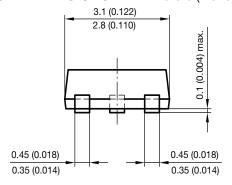
Fig. 3 - Typical Reverse Voltage  $V_{\text{R}}$  vs. Reverse Current  $I_{\text{R}}$ 

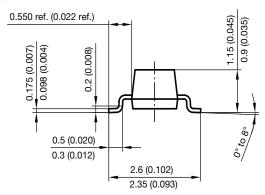


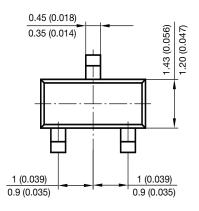
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## PACKAGE DIMENSIONS in millimeters (inches): SOT-23

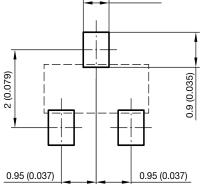






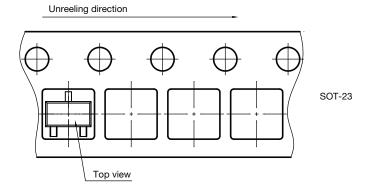


Foot print recommendation:



Document no.: 6.541-5014.01-4 Rev. 8 - Date: 23.Sept.2009

17418



Orientation in carrier tape SOT-23 S8-V-3929.01-006 (4) 04.02.2010 22607



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Revision: 13-Jun-16 1 Document Number: 91000